

**TX-IF SiMMIC FOR W-CDMA
ACG + I/Q MODULATOR**

UPC8191K

FEATURES

- **LOW POWER CONSUMPTION:**
Vcc = 3.0 V
- **SMALL 20 PIN QFN PACKAGE:**
Flat lead style for better performance
- **TAPE AND REEL PACKAGING AVAILABLE**

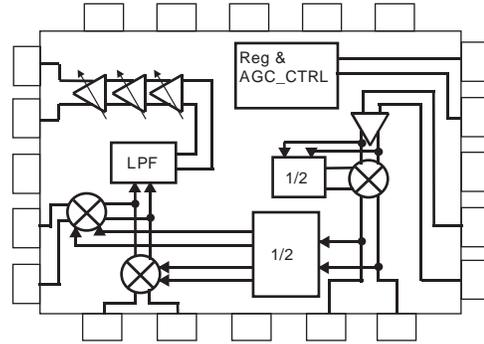
DESCRIPTION

The UPC8191K is a Silicon Microwave Monolithic Integrated Circuit designed as a transmitter/TX section for W-CDMA. The UPC8191K is a TX-IF IC including IF-AGC amplifier and modulator. This IC is suitable for kit-use for W-CDMA IF section.

This IC was developed using NEC's new ultra high seed silicon bipolar process.

NEC's stringent quality assurance and test procedures ensure the highest reliability and performance.

BLOCK DIAGRAM



APPLICATIONS

- **W-CDMA**

ELECTRICAL CHARACTERISTICS (unless otherwise specified, $T_A = 25^\circ\text{C}$, $V_{CC} = 3.0\text{ V}$, $f_{IF} = 570\text{ MHz}$, $f_{LO} = 760\text{ MHz}$, $P_{LO} = -15\text{ dBm}$, $f_{I/Q} = 10\text{ kHz}$, 400 mVp-p balanced sine-wave)

PART NUMBER PACKAGE OUTLINE			UPC8191K QFN-20		
SYMBOLS	PARAMETERS AND CONDITIONS	UNITS	MIN	TYP	MAX
I _{CC}	Circuit Current, No Signals At power saving mode	mA	-	30.5	38
		μA	-	0	1
P _{OUT}	Output Power, V _{CONT} = 2.3 V, I/Q = 400mVp-p balanced V _{CONT} = 0.3 V, I/Q = 400mVp-p balanced	dBm	-17	-13	-
			-	-93	-88
LoL	Local Leakage, V _{CONT} = 2.3 V, I/Q = 400mVp-p balanced	dBc	-	-	-30
IoL	Image Leakage, V _{CONT} = 2.3 V, I/Q = 400mVp-p balanced	dBc	-	-	-30
	Output Harmonics 1, Leakage when IF output = 190 MHz	dBc	-	-	-20
	Output Harmonics 2, Leakage when IF output = 380 MHz	dBc	-	-	-30
T _{PS(Rise)}	Rise time from power-saving mode	us	-	-	10
V _{PS(Rise)}	Rising voltage from power-saving mode	V	-	-	2.2
V _{PS(fall)}	Falling voltage from power-saving mode	V	0.5	-	-

STANDARD CHARACTERISTICS FOR REFERENCE (unless otherwise specified, $T_A = 25^\circ\text{C}$, $V_{CC} = 3.0\text{ V}$, $f_{IF} = 570\text{ MHz}$, $f_{LO} = 760\text{ MHz}$, $P_{LO} = -15\text{ dBm}$, $f_{I/Q} = 10\text{ kHz}$, 400 mVp-p balanced sine-wave)

PART NUMBER PACKAGE OUTLINE			UPC8191K QFN-20		
SYMBOLS	PARAMETERS AND CONDITIONS	UNITS	MIN	TYP	MAX
	Output Noise Level 1, P _{out} = -25 dBm, f _{IF} ±20MHz	dBm/Hz	-	-148	-
	Output Noise Level 1, P _{out} = -65 dBm, f _{IF} ±20MHz	dBm/Hz	-	-162	-
GF	Gain Flatness, f _{IF} ±2.5MHz	dB	-	-	0.5
EVM	Error Vector Magnitude, I/Q = 3.84 Msps QPSK	%rms	-	3	-
ACPR	f _{IF} ±5 MHz, I/Q=3.84 Msps QPSK	dBc	-	-55	-

ABSOLUTE MAXIMUM RATINGS¹ (TA = 25°C)

SYMBOLS	PARAMETERS	UNITS	RATINGS
Vcc	Supply Voltage	V	4.0
Vps, VCONT	Applied Voltage	V	-0.3 to Vcc +0.3
TA	Operating Ambient Temperature	°C	-40 to +85
TSTG	Storage Temperature	°C	-55 to +150

Notes:

1. Operation in excess of any one of these parameters may result in permanent damage.

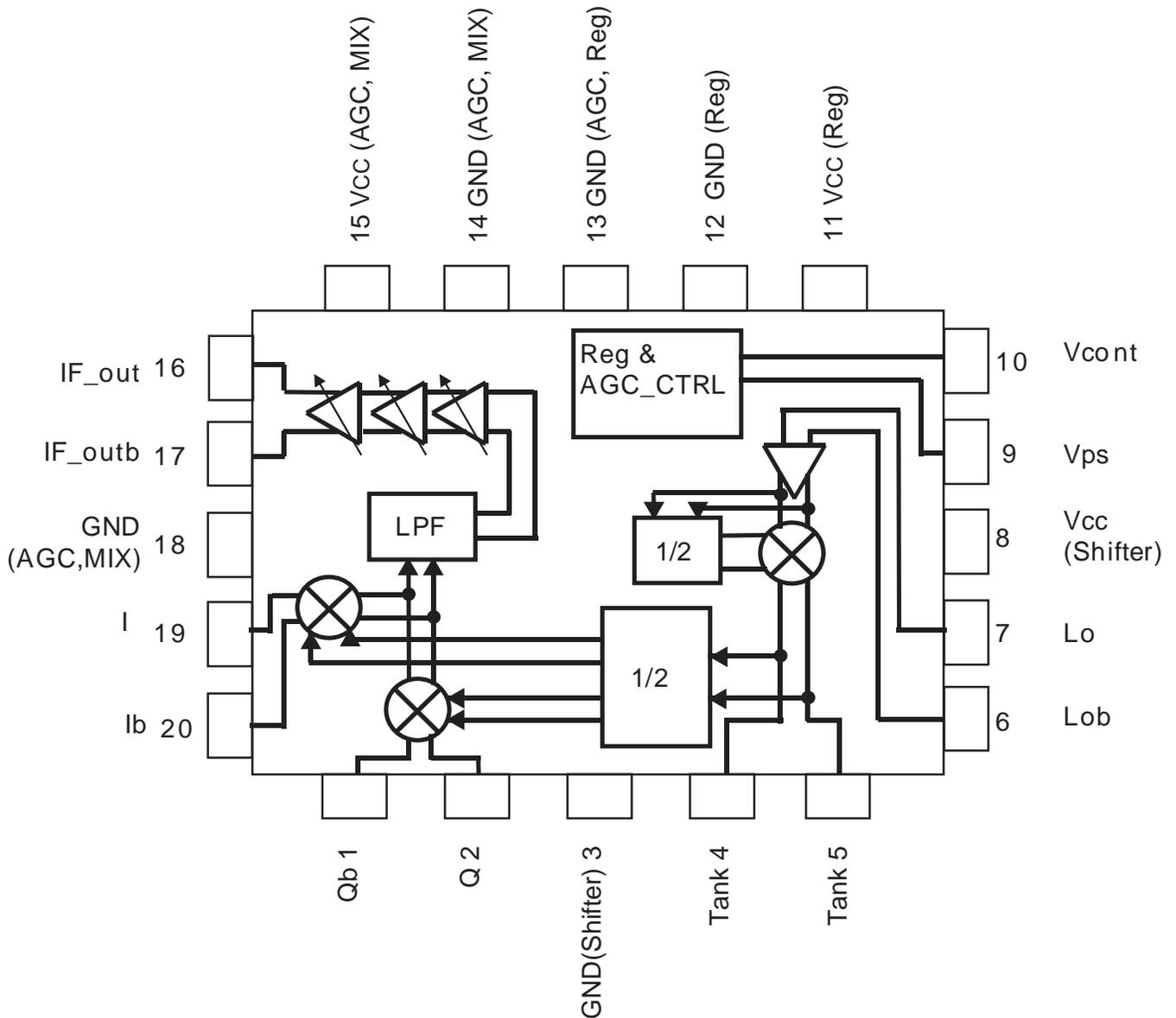
RECOMMENDED OPERATING CONDITIONS

SYMBOLS	PARAMETERS	UNITS	MIN	TYP	MAX
Vcc	Supply Voltage	V	2.7	3.0	3.3
TA	Operating Ambient Temperature	°C	-25	+25	+85
fiF	IF Frequency	MHz	-	570	-
fiLo	Local Frequency	MHz	-	760	-
PLo	Local input Level	dBm	-18	-15	-12
ZIF	IF output impedance, Balanced output internal resistance	kΩ	-	1	-
VI/Q	I/Q Maximum Input Voltage	V	-	-	1

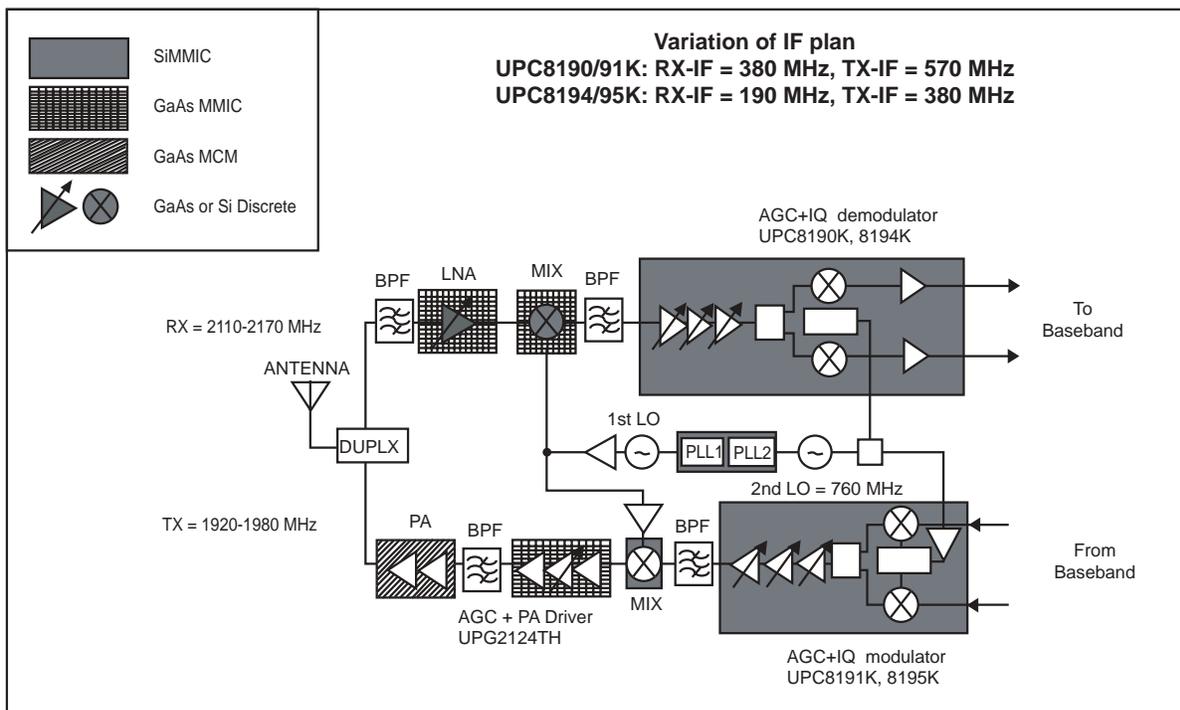
ORDERING INFORMATION

Part Number	Package
UPC8191K-E1	20 Pin plastic QFN

BLOCK DIAGRAM (Units in mm)

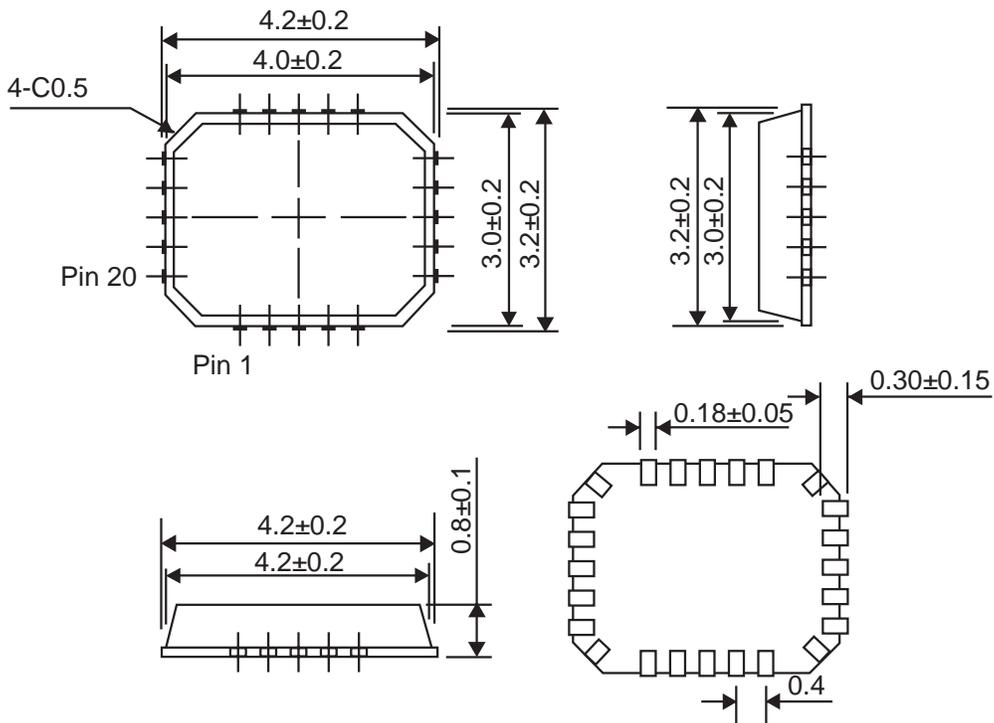


APPLICATION EXAMPLE: W-CDMA



OUTLINE DIMENSIONS (Units in mm)

Package Outline QFN-20



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